

● HEADPHONE™

SRS Headphone 3D SURROUND PROCESSOR

■ GENERAL DESCRIPTION

The NJM2190 is a headphone surround processor based on SRS technology. It provides a realistic and spacious listening experience through standard headphones.

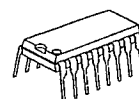
The features of low operating voltage, low output noise, and low operating current are very suitable for portable audio applications.

■ FEATURES

- Operating Voltage (1.8 to 6.0V)
- Low Operating Current (1.3mA typ. at SRS mode)
- Low Output Noise (12.0 μ Vrms typ. at SRS mode)
- WIDTH Control
- Bipolar Technology
- Package Outline

DIP16, DMP16, SSOP16

■ PACKAGE OUTLINE



NJM2190D



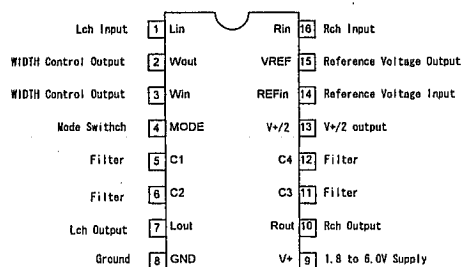
NJM2190M



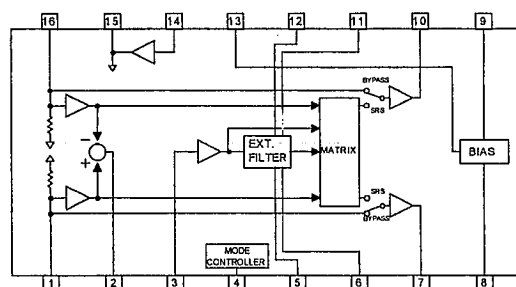
NJM2190V

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■ PIN CONFIGURATION



■ BLOCK DIAGRAM



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■ ABSOLUTE MAXIMUM RATING (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺	7	V
Power Dissipation	P _D	(DIP16) 500 (DMP16) 300 (SSOP16) 300	mW
Operating Temperature Range	T _{opr}	-20 to +75	°C
Storage Temperature Range	T _{stg}	-40 to +125	°C

■ ELECTRICAL CHARACTERISTICS (V⁺=3V, V_{IN}=-26dBV (50mVrms), Ta=25°C, unless otherwise specified.)

PARAMETER	SYMBOL		CONDITION					MIN	TYP	MAX	UNIT
			INPUT		OUTPUT	MODE	WIDTH VR(*1)				
			L	R							
Operating Voltage	V ⁺		-	-	-	-	-	1.8	3.0	6.0	V
Operating Current	I _{CC}	No Signal	0	0	-	BYPASS	-	-	0.7	1.0	mA
			0	0	-	SRS	MIN	-	1.3	1.8	
			0	0	-	SRS	MAX	-	1.3	1.8	
Reference Voltage	V _{REF}	V ⁺ /2	-	-	-	-	-	1.3	1.5	1.7	V
Maximum Input Voltage	V _{IM}	f=1kHz THD=1%	V _{IN}	0	L	BYPASS	-	-	0.1 (1012)	-	dBV (mVrms)
			0	V _{IN}	R						
		f=100Hz THD=1%	V _{IN}	0	L	SRS	MIN	-	-11.8 (257)	-	
			0	V _{IN}	R						
		f=100Hz THD=1%	V _{IN}	0	L	SRS	MAX	-	-15.8 (162)	-	
			0	V _{IN}	R						
		V ⁺ =1.8V f=1kHz THD=1%	V _{IN}	0	L	BYPASS	-	-6.7 (462)	-4.7 (582)	-	
			0	V _{IN}	R						
		V ⁺ =1.8V f=100Hz THD=1%	V _{IN}	0	L	SRS	MIN	-	-16.7 (146)	-	
			0	V _{IN}	R						
		V ⁺ =1.8V f=100Hz THD=1%	V _{IN}	0	L	SRS	MAX	-22.5 (75)	-20.5 (94)	-	
			0	V _{IN}	R						

■ ELECTRICAL CHARACTERISTICS ($V^+=3V$, $V_{IN}=-26dBV(50mVrms)$, $T_a=25^\circ C$, unless otherwise specified.)

PARAMETER	SYMBOL		CONDITION					MIN	TYP	MAX	UNIT
			INPUT		OUTPUT	MODE	WIDTH VR(*1)				
			L	R							
Maximum Input Voltage (*2)	V _{IM}	V ⁺ =1.8V f=1kHz THD=1%	V _{IN}	V _{IN}	L	SRS	MIN	-	-16.7 (146)	-	dBV (mVrms)
					R						
			V _{IN}	V _{IN}	L	SRS	MAX	-	-16.7 (146)	-	
					R						
		V ⁺ =1.8V f=100Hz THD=1%	V _{IN}	-V _{IN}	L	SRS	MIN	-	-22.9 (72)	-	
					R						
		V ⁺ =1.8V f=100Hz THD=1%	V _{IN}	-V _{IN}	L	SRS	MAX	-28.5 (38)	-26.5 (47)	-	
					R						
Output Noise	V _{NO}	R _g =0 Ω A-Weighted	0	0	L	BYPASS	-	-	-110 (3.0)	-104 (6.0)	dBV (μVrms)
					R						
			0	0	L	SRS	MIN	-	-98 (12.0)	-	
					R						
			0	0	L	SRS	MAX	-	-98 (12.0)	-92 (24.0)	
					R						
Total Harmonic Distortion	THD	V ⁺ =1.8V f=1kHz	V _{IN}	0	L	BYPASS	-	-	0.02	-	%
			0	V _{IN}	R						
			V _{IN}	0	L	SRS	MIN	-	0.10	-	
			0	V _{IN}	R						
			V _{IN}	0	L	SRS	MAX	-	0.25	0.5	
			0	V _{IN}	R						
BYPASS Gain	G _{VBYP}	f=1kHz	V _{IN}	0	L	BYPASS	-	-1.0	0.0	1.0	dB
			0	V _{IN}	R						
L + R Gain	G _{L+R}	f=1kHz	V _{IN}	V _{IN}	L	SRS	MIN	-	0.0	-	dB
					R						
			V _{IN}	V _{IN}	L	SRS	MAX	-1.0	0.0	1.0	
					R						

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■ ELECTRICAL CHARACTERISTICS ($V^+=3V$, $V_{IN}=-26dBV$ (50mVrms), $T_a=25^\circ C$, unless otherwise specified.)

PARAMETER	SYMBOL		CONDITION					MIN	TYP	MAX	UNIT
			INPUT		OUTPUT	MODE	WIDTH VR ^(*)				
			L	R							
L-R Gain (*2)	G _{L-R}	f=100Hz	V _{IN}	-V _{IN}	L	SRS	MIN	3.7	5.7	7.7	dB
					R						
			V _{IN}	-V _{IN}	L	SRS	MAX	19.3	21.3	23.3	
					R						
Channel Separation	CS	f=1kHz	0	V _{IN}	L	BYPASS	-	60.0	80.0	-	dB
			V _{IN}	0	R						
MODE Select Control Voltage	V _{IH}	High Level	-	-	-	-	-	1.3	-	V ⁺	V
	V _{IL}	Low Level	-	-	-	-	-	0.0	-	0.5	

(*)1 Refer to application circuit 1.

(*)2 The word ' $-V_{IN}$ ' signifies opposite phase of ' V_{IN} '.

■ MODE Switch

	MODE
BYPASS MODE	L
SRS MODE	H

■ TERMINAL DESCRIPTION

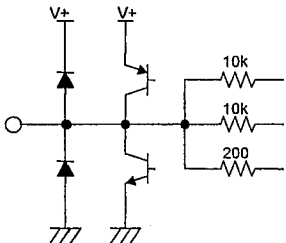
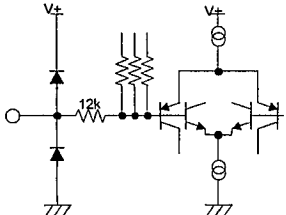
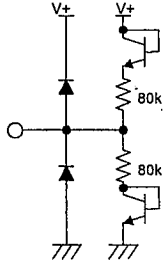
PIN NO.	SYMBOL	FUNCTION	EQUIVALENT CIRCUIT	VOLTAGE
1 16	Lin Rin	Audio Input		$V^+/2$
2	Wout	WIDTH Control Output		$V^+/2$
3	Win	WIDTH Control Input		$V^+/2$
4	MODE	Mode Switch		-

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■ TERMINAL DESCRIPTION

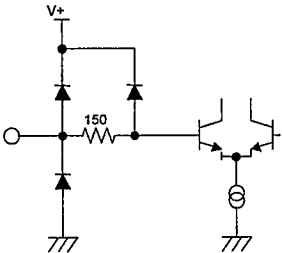
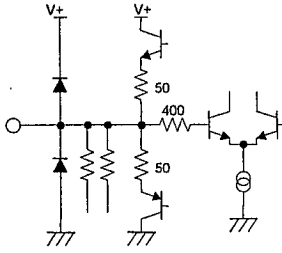
PIN NO.	SYMBOL	FUNCTION	EQUIVALENT CIRCUIT	VOLTAGE
5	C1	Capacitor Terminal 1 for Filter		$V^+/2$
6	C2	Capacitor Terminal 2 for Filter		$V^+/2$
7 10	Lout Rout	Audio Output		$V^+/2$
8	GND	Ground		0V

■ TERMINAL DESCRIPTION

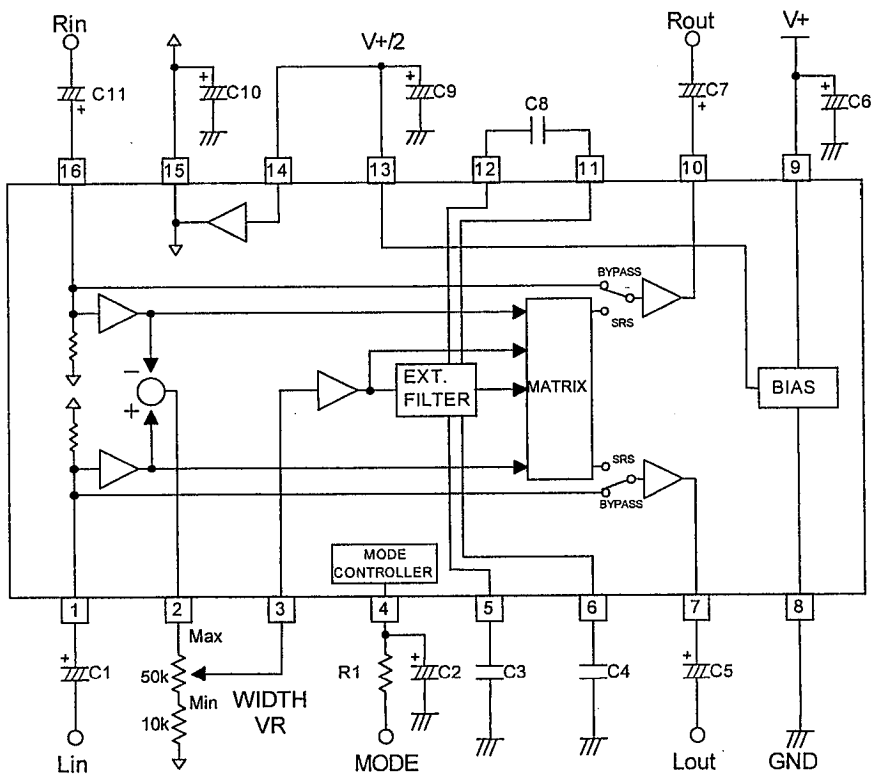
PIN NO.	SYMBOL	FUNCTION	EQUIVALENT CIRCUIT	VOLTAGE
9	V ⁺	Power Supply		V ⁺
11	C3	Capacitor Terminal 3 for Filter		V ⁺ /2
12	C4	Capacitor Terminal 4 for Filter		V ⁺ /2
13	V ⁺ /2	V ⁺ /2 Output		V ⁺ /2

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■ TERMINAL DESCRIPTION

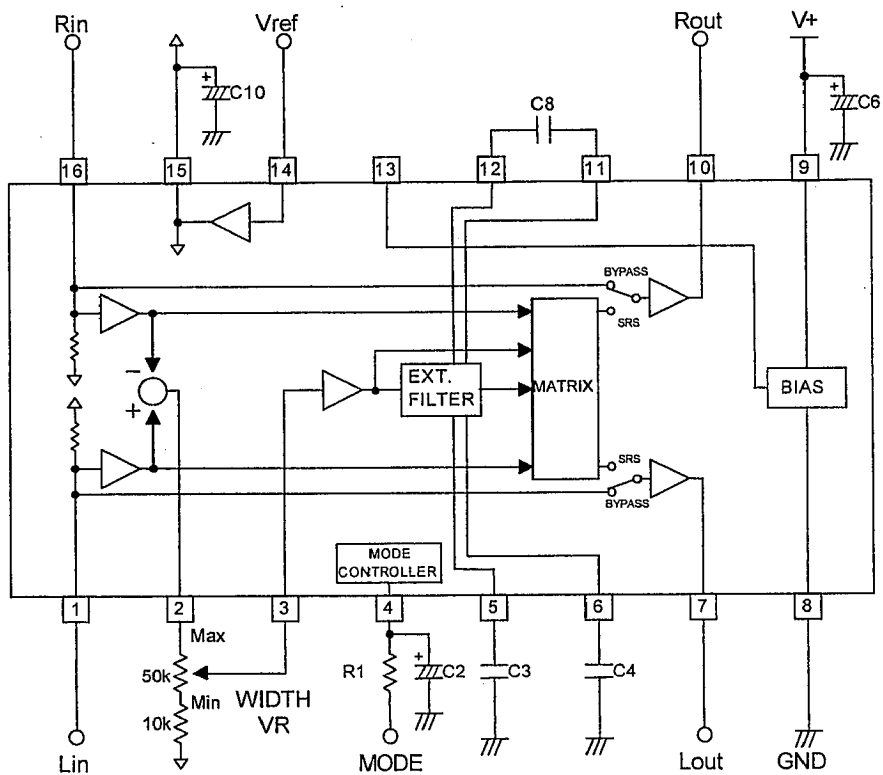
PIN NO.	SYMBOL	FUNCTION	EQUIVALENT CIRCUIT	VOLTAGE
14	REFin	Reference Voltage Input		$V^+/2$
15	VREF	Reference Voltage Output		$V^+/2$

APPLICATION CIRCUIT 1



Parts No.	Value	Tolerance	Parts No.	Value	Tolerance
R1	22k Ω	$\pm 5\%$	C6	22 to 100 μ F	-
C1	10 μ F	-	C7	10 μ F	-
C2	10 μ F	-	C8	4.7nF	$\pm 5\%$
C3	3.3nF	$\pm 5\%$	C9	1 to 10 μ F	-
C4	0.1 μ F	$\pm 5\%$	C10	10 to 7 μ F	-
C5	10 μ F	-	C11	10 μ F	-

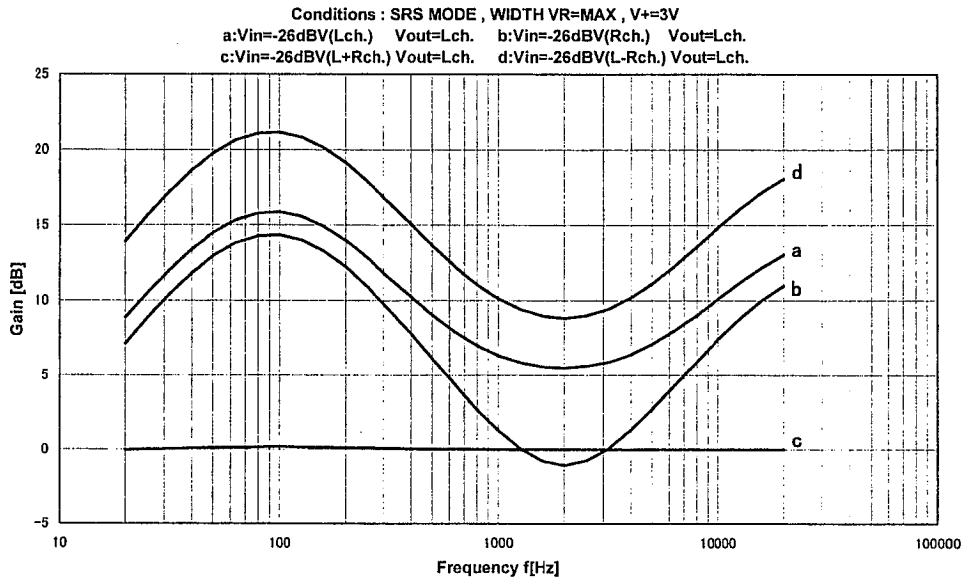
■ APPLICATION CIRCUIT 2 (Without using internal $V_{+}/2$.)



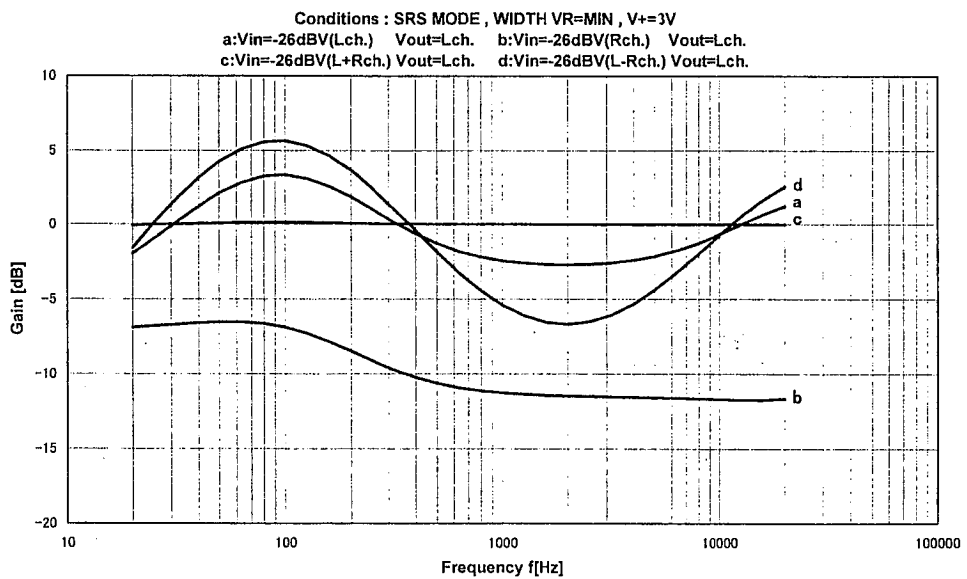
Parts No.	Value	Tolerance	Parts No.	Value	Tolerance
R1	22k Ω	$\pm 5\%$	C6	22 to 100 μF	–
C2	10 μF	–	C8	4.7nF	$\pm 5\%$
C3	3.3nF	$\pm 5\%$	C10	10 to 47 μF	–
C4	0.1 μF	$\pm 5\%$			

■ TYPICAL CHARACTERISTICS

GAIN STRUCTURE (WIDTH VR:MAX)



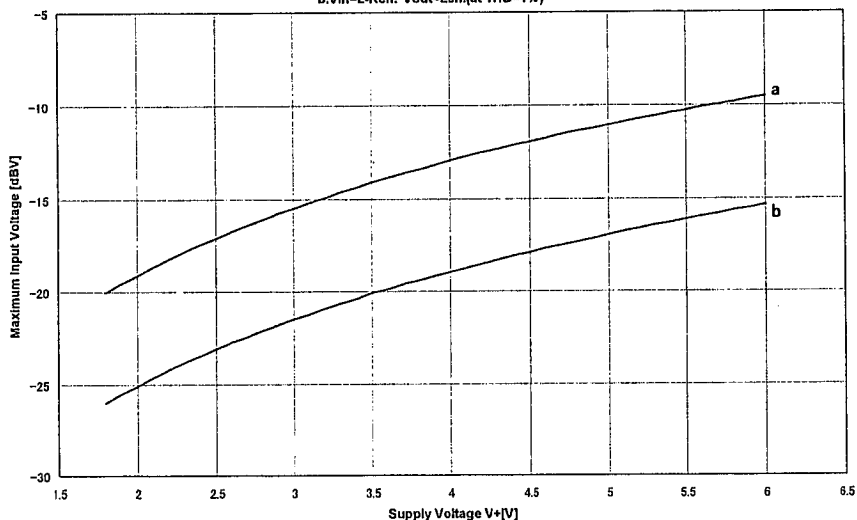
GAIN STRUCTURE (WIDTH VR:MIN)



TYPICAL CHARACTERISTICS

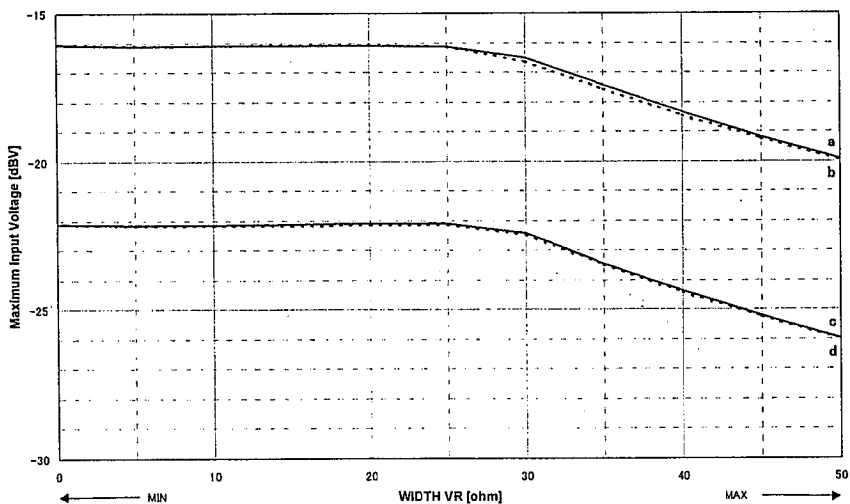
Maximum Input Voltage vs. Supply Voltage

Maximum Input Voltage vs. Supply Voltage
 conditions : SRS MODE, WIDTH VR=MAX, $f=100\text{Hz}$
 a. $V_{in}=Lch.$ $V_{out}=Lch.$ (at THD=1%)
 b. $V_{in}=L-Rch.$ $V_{out}=Lch.$ (at THD=1%)



Maximum Input Voltage vs. WIDTH VR

Conditions : SRS MODE, $V+=1.8V$, $f=100\text{Hz}$
 a: $V_{in}=Lch.$ $V_{out}=Lch.$ (at THD=1%) b: $V_{in}=Lch.$ $V_{out}=Rch.$ (at THD=1%)
 c: $V_{in}=L-Rch.$ $V_{out}=Lch.$ (at THD=1%) d: $V_{in}=L-Rch.$ $V_{out}=Rch.$ (at THD=1%)



MEMO

[CAUTION]

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